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CD4528BM/CD4528BC Dual Monostable Multivibrator

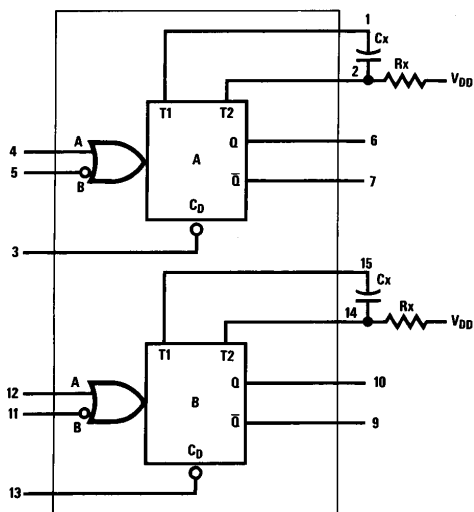
General Description

The CD4528B is a dual monostable multivibrator. Each device is retriggerable and resettable. Triggering can occur from either the rising or falling edge of an input pulse, resulting in an output pulse over a wide range of widths. Pulse duration and accuracy are determined by external timing components Rx and Cx.

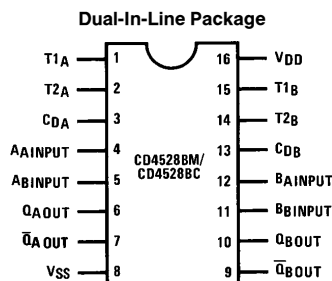
Features

- Wide supply voltage range 3.0V to 18V
- Separate reset available
- Quiescent current = 5.0 nA/package (typ.) at 5.0 V_{DC}
- Diode protection on all inputs
- Triggerable from leading or trailing edge pulse
- Capable of driving two low-power TTL loads or one low-power Schottky TTL load over the rated temperature range

Connection Diagrams



TL/F/5998-1



TL/F/5998-2

Top View
Order Number CD4528B

Truth Table

Inputs			Outputs	
Clear	A	B	Q	Q
L	X	X	L	H
X	H	X	L	H
X	X	L	L	H
H	L	↓	⌊	⌋
H	↑	H	⌋	⌊

H = High Level
L = Low Level
↑ = Transition from Low to High
↓ = Transition from High to Low
⌊ = One High Level Pulse
⌋ = One Low Level Pulse
X = Irrelevant

Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

DC Supply Voltage (V_{DD}) $-0.5 V_{DC}$ to $+18 V_{DC}$

Input Voltage, All Inputs (V_{IN}) $-0.5 V_{DC}$ to $V_{DD} + 0.5 V_{DC}$

Storage Temperature Range (T_S) -65°C to $+150^{\circ}\text{C}$

Power Dissipation (P_D)
Dual-In-Line 700 mW
Small Outline 500 mW

Lead Temperature (T_L)
(Soldering, 10 seconds) 260°C

Recommended Operating Conditions (Note 2)

DC Supply Voltage (V_{DD}) 3V to 15V

Input Voltage (V_{IN}) 0V to V_{DD}

Operating Temperature Range (T_A)
CD4528BM -55°C to $+125^{\circ}\text{C}$
CD4528BC -40°C to $+85^{\circ}\text{C}$

DC Electrical Characteristics CD4528BM (Note 2)

Symbol	Parameter	Conditions	-55°C		$+25^{\circ}\text{C}$			$+125^{\circ}\text{C}$		Units
			Min	Max	Min	Typ	Max	Min	Max	
I_{DD}	Quiescent Device Current	$V_{DD} = 5\text{V}$		5	0.005		5		150	μA
		$V_{DD} = 10\text{V}$		10	0.010		10		300	μA
		$V_{DD} = 15\text{V}$		20	0.015		20		600	μA
V_{OL}	Low Level Output Voltage	$V_{DD} = 5\text{V}$		0.05			0.05		0.05	V
		$V_{DD} = 10\text{V}$		0.05			0.05		0.05	V
		$V_{DD} = 15\text{V}$		0.05			0.05		0.05	V
V_{OH}	High Level Output Voltage	$V_{DD} = 5\text{V}$	4.95		4.95	5.0		4.95		V
		$V_{DD} = 10\text{V}$	9.95		9.95	10.0		9.95		V
		$V_{DD} = 15\text{V}$	14.95		14.95	15.0		14.95		V
V_{IL}	Low Level Input Voltage	$V_{DD} = 5\text{V}, V_O = 0.5\text{V}$ or 4.5V		1.5		2.25	1.5		1.5	V
		$V_{DD} = 10\text{V}, V_O = 1\text{V}$ or 9V		3.0		4.50	3.0		3.0	V
		$V_{DD} = 15\text{V}, V_O = 1.5\text{V}$ or 13.5V		4.0		6.75	4.0		4.0	V
V_{IH}	High Level Input Voltage	$V_{DD} = 5\text{V}, V_O = 0.5\text{V}$ or 4.5V	3.5		3.5	2.75		3.5		V
		$V_{DD} = 10\text{V}, V_O = 1\text{V}$ or 9V	7.0		7.0	5.50		7.0		V
		$V_{DD} = 15\text{V}, V_O = 1.5\text{V}$ or 13.5V	11.0		11.0	8.25		11.0		V
I_{OL}	Low Level Output Current (Note 3)	$V_{DD} = 5\text{V}, V_O = 0.4\text{V}$	0.64		0.51	0.88		0.36		mA
		$V_{DD} = 10\text{V}, V_O = 0.5\text{V}$	1.6		1.3	2.25		0.9		mA
		$V_{DD} = 15\text{V}, V_O = 1.5\text{V}$	4.2		3.4	8.8		2.4		mA
I_{OH}	High Level Output Current (Note 3)	$V_{DD} = 5\text{V}, V_O = 4.6\text{V}$	-0.25		-0.2	-0.36		-0.14		mA
		$V_{DD} = 10\text{V}, V_O = 9.5\text{V}$	-0.62		-0.5	-0.9		-0.35		mA
		$V_{DD} = 15\text{V}, V_O = 13.5\text{V}$	-1.8		-1.5	-3.5		-1.1		mA
I_{IN}	Input Current	$V_{DD} = 15\text{V}, V_{IN} = 0\text{V}$		-0.1		-10^{-5}	-0.1		-1.0	μA
		$V_{DD} = 15\text{V}, V_{IN} = 15\text{V}$		0.1		10^{-5}	0.1		1.0	μA

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range", they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: $V_{SS} = 0\text{V}$ unless otherwise specified.

Note 3: I_{OH} and I_{OL} are tested one output at a time.

DC Electrical Characteristics CD4528BC (Note 2)

Symbol	Parameter	Conditions	− 40°C		+ 25°C			+ 85°C		Units
			Min	Max	Min	Typ	Max	Min	Max	
I _{DD}	Quiescent Device Current	V _{DD} = 5V		20		0.005	20		150	μA
		V _{DD} = 10V		40		0.010	40		300	μA
		V _{DD} = 15V		80		0.015	80		600	μA
V _{OL}	Low Level Output Voltage	V _{DD} = 5V		0.05			0.05		0.05	V
		V _{DD} = 10V		0.05			0.05		0.05	V
		V _{DD} = 15V		0.05			0.05		0.05	V
V _{OH}	High Level Output Voltage	V _{DD} = 5V	4.95		4.95	5.0		4.95		V
		V _{DD} = 10V	9.95		9.95	10.0		9.95		V
		V _{DD} = 15V	14.95		14.95	15.0		14.95		V
V _{IL}	Low Level Input Voltage	V _{DD} = 5V, V _O = 0.5V or 4.5V		1.5		2.25	1.5		1.5	V
		V _{DD} = 10V, V _O = 1V or 9V		3.0		4.50	3.0		3.0	V
		V _{DD} = 15V, V _O = 1.5V or 13.5V		4.0		6.75	4.0		4.0	V
V _{IH}	High Level Input Voltage	V _{DD} = 5V, V _O = 0.5V or 4.5V	3.5		3.5	2.75		3.5		V
		V _{DD} = 10V, V _O = 1V or 9V	7.0		7.0	5.50		7.0		V
		V _{DD} = 15V, V _O = 1.5V or 13.5V	11.0		11.0	8.25		11.0		V
I _{OL}	Low Level Output Current (Note 3)	V _{DD} = 5V, V _O = 0.4V	0.52		0.44	0.88		0.36		mA
		V _{DD} = 10V, V _O = 0.5V	1.3		1.1	2.25		0.9		mA
		V _{DD} = 15V, V _O = 1.5V	3.6		3.0	8.8		2.4		mA
I _{OH}	High Level Output Current (Note 3)	V _{DD} = 5V, V _O = 4.6V	−0.2		−0.16	−0.36		−0.12		mA
		V _{DD} = 10V, V _O = 9.5V	−0.5		−0.4	−0.9		−0.3		mA
		V _{DD} = 15V, V _O = 13.5V	−1.4		−1.2	−3.5		−1.0		mA
I _{IN}	Input Current	V _{DD} = 15V, V _{IN} = 0V		−0.3		−10 ^{−5}	−0.3		−1.0	μA
		V _{DD} = 15V, V _{IN} = 15V		0.3		10 ^{−5}	0.3		1.0	μA

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range", they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: V_{SS} = 0V unless otherwise specified.

Note 3: I_{OH} and I_{OL} are tested one output at a time.

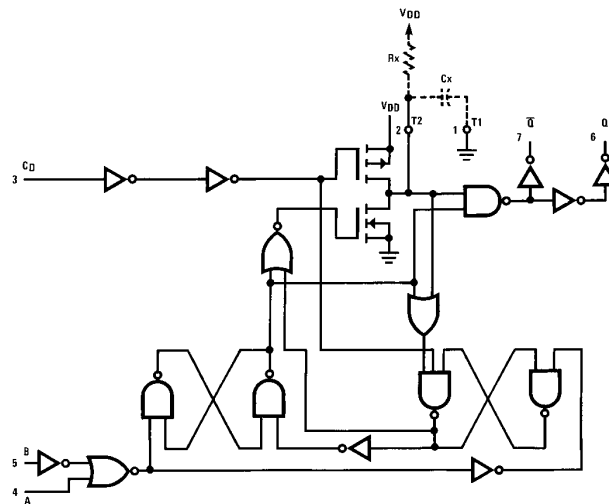
AC Electrical Characteristics* CD4528BM

T_A = 25°C, C_L = 50 pF, R_L = 200 kΩ, Input t_r = t_f = 20 ns, unless otherwise specified

Parameter	Conditions	Min	Typ	Max	Units
Output Rise Time	t _r = (3.0 ns/pF) C _L + 30 ns, V _{DD} = 5.0V		180	400	ns
	t _r = (1.5 ns/pF) C _L + 15 ns, V _{DD} = 10.0V		90	200	ns
	t _r = (1.1 ns/pF) C _L + 10 ns, V _{DD} = 15.0V		65	160	ns
Output Fall Time	t _f = (1.5 ns/pF) C _L + 25 ns, V _{DD} = 5.0V		100	200	ns
	t _f = (0.75 ns/pF) C _L + 12.5 ns, V _{DD} = 10V		50	100	ns
	t _f = (0.55 ns/pF) C _L + 9.5 ns, V _{DD} = 15.0V		35	80	ns
Turn-Off, Turn-On Delay A or B to Q or $\bar{Q}$ C _x = 15 pF, R _x = 5.0 kΩ	t _{PLH} , t _{PHL} = (1.7 ns/pF) C _L + 240 ns, V _{DD} = 5.0V		230	500	ns
	t _{PLH} , t _{PHL} = (0.66 ns/pF) C _L + 8 ns, V _{DD} = 10.0V		100	250	ns
	t _{PLH} , t _{PHL} = (0.5 ns/pF) C _L + 65 ns, V _{DD} = 15.0V		65	150	ns
Turn-Off, Turn-On Delay A or B to Q or $\bar{Q}$ C _x = 100 pF, R _x = 10 kΩ	t _{PLH} , t _{PHL} = (1.7 ns/pF) C _L + 620 ns, V _{DD} = 5.0V		230	500	ns
	t _{PLH} , t _{PHL} = (0.66 ns/pF) C _L + 257 ns, V _{DD} = 10.0V		100	250	ns
	t _{PLH} , t _{PHL} = (0.5 ns/pF) C _L + 185 ns, V _{DD} = 15.0V		65	150	ns
Minimum Input Pulse Width A or B C _x = 15 pF, R _x = 5.0 kΩ	V _{DD} = 5.0V		60	150	ns
	V _{DD} = 10.0V		20	50	ns
	V _{DD} = 15V		20	50	ns
C _x = 1000 pF, R _x = 10 kΩ	V _{DD} = 5.0V		60	150	ns
	V _{DD} = 10.0V		20	50	ns
	V _{DD} = 15.0V		20	50	ns
Output Pulse Width Q or $\bar{Q}$ For C _x < 0.01 μF (See Graph for Appropriate V _{DD} Level) C _x = 15 pF, R _x = 5.0 kΩ	V _{DD} = 5.0V		550		ns
	V _{DD} = 10.0V		350		ns
	V _{DD} = 15.0V		300		ns
For C _x > 0.01 μF Use PW _{out} = 0.2 R _x C _x ln [V _{DD} - V _{SS}] C _x = 10,000 pF, R _x = 10 kΩ	V _{DD} = 5.0V	15	29	45	μs
	V _{DD} = 10.0V	10	37	90	μs
	V _{DD} = 15.0V	15	42	95	μs
Pulse Width Match between Circuits in the Same Package C _x = 10,000 pF, R _x = 10 kΩ	V _{DD} = 5.0V		6	25	%
	V _{DD} = 10.0V		8	35	%
	V _{DD} = 15.0V		8	35	%
Reset Propagation Delay, t _{PLH} , t _{PHL} C _x = 15 pF, R _x = 5.0 kΩ	V _{DD} = 5.0V		325	600	ns
	V _{DD} = 10.0V		90	225	ns
	V _{DD} = 15.0V		60	170	ns
C _x = 1000 pF, R _x = 10 kΩ	V _{DD} = 5.0V		7.0		μs
	V _{DD} = 10.0V		6.7		μs
	V _{DD} = 15.0V		6.7		μs
Minimum Retrigger Time C _x = 15 pF, R _x = 5.0 kΩ C _x = 1000 pF, R _x = 10 kΩ	V _{DD} = 5.0V		0		ns
	V _{DD} = 10.0V		0		ns
	V _{DD} = 15.0V		0		ns
	V _{DD} = 5.0V		0		ns
	V _{DD} = 10.0V		0		ns
	V _{DD} = 15.0V		0		ns

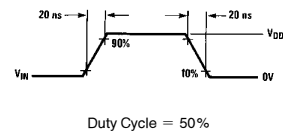
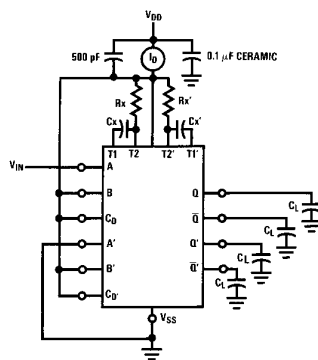
*AC parameters are guaranteed by DC correlated testing.

Logic Diagrams (1/2 of Device Shown)



Note: Externally ground pins 1 and 15 to pin 8.

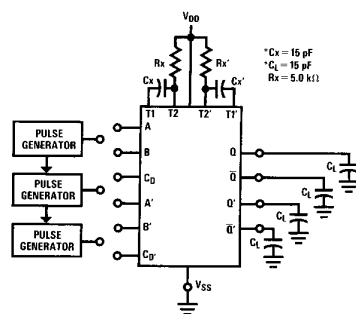
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TL/F/5998-10

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FIGURE 1. Power Dissipation Test Circuit and Waveforms



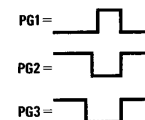
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Input Connections

Characteristics	C _D	A	B
t _{PLH} , t _{PHL} , t _r , t _f , PW _{out} , PW _{in}	V _{DD}	PG1	V _{DD}
t _{PLH} , t _{PHL} , t _r , t _f , PW _{out} , PW _{in}	V _{DD}	V _{SS}	PG2
t _{PLH(R)} , t _{PHL(R)} , PW _{in}	PG3	PG1	PG2

*Includes capacitance of probes, wiring, and fixture parasitic.

Note: AC test waveforms for PG1, PG2, and PG3 on next page.



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FIGURE 2. AC Test Circuit

TL/F/5998-7



This graph shows the relationship between Pulse Width (PW) in microseconds and External Capacitance (Cx) in picofarads for different load resistances (Rx) and supply voltages (V). The y-axis is logarithmic, ranging from 0.1 to 5000.0 μ s. The x-axis is logarithmic, ranging from 10 to 1,000,000 pF. Three sets of curves are shown for Rx = 100k, Rx = 10k, and Rx = 5k. Within each set, three curves represent V = 15V (solid line), V = 10V (dotted line), and V = 5V (dashed line). The curves show that PW increases with Cx and decreases with higher V and lower Rx.

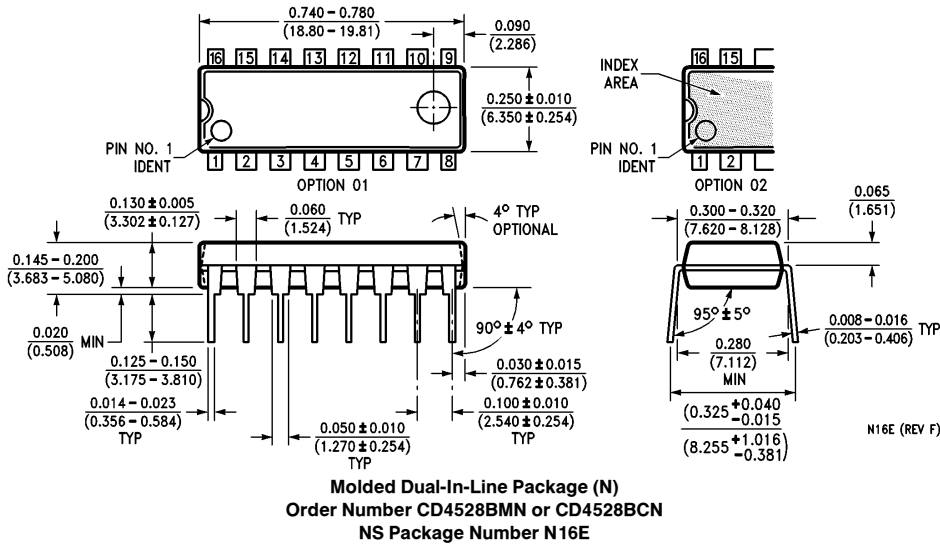
Cx (pF)	Rx = 100k			Rx = 10k			Rx = 5k		
	V = 15V	V = 10V	V = 5V	V = 15V	V = 10V	V = 5V	V = 15V	V = 10V	V = 5V
100	~10	~5	~3	~1	~0.5	~0.3	~0.5	~0.3	~0.2
1,000	~100	~50	~30	~10	~5	~3	~5	~3	~2
10,000	~1,000	~500	~300	~100	~50	~30	~50	~30	~20
100,000	~10,000	~5,000	~3,000	~1,000	~500	~300	~500	~300	~200

TL/F/5998-9

[illegible]

J16A (REV L)

Physical Dimensions inches (millimeters) (Continued)



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